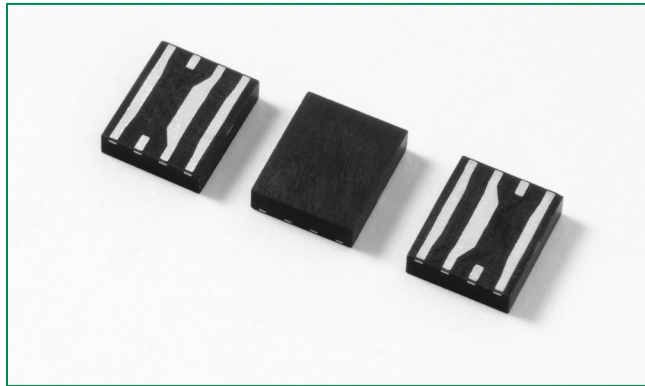


SDP Biased Series - 5x6 QFN



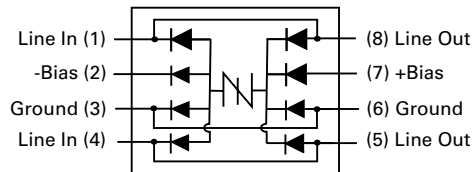
Agency Approvals

Agency	Agency File Number
	E133083

Pinout Designation

Tip in	1	8	Tip out
- Bias	2	7	+ Bias
Ground	3	6	Ground
Ring in	4	5	Ring out

Schematic Symbol



Description

This new SDP Biased series provides overvoltage protection for applications such as VDSL2, ADSL2, and ADSL2+ with minimal effect on data signals. This latest silicon design innovation results in a capacitive loading characteristic that is compatible with these high bandwidth applications. This surface mount QFN package provides a surge capability that exceeds most worldwide standards and recommendations for lightning surge withstand capability of secondary protectors.

Features & Benefits

- Compatible with VDSL2 (30MHz)
- Balanced overvoltage protection
- Low distortion
- Low insertion loss
- Low profile
- SO-8 footprint compatible
- Fails short circuit when surged in excess of ratings
- 2nd level interconnect is Pb-free per IPC/JEDEC J-STD-609A.01

Applicable Global Standards

- TIA-968-A
- TIA-968-B
- ITU K.20/21 Enhanced Level
- ITU K.20/21 Basic Level
- IEC 61000-4-5
- GR 1089 Inter-building
- GR 1089 Intra-building
- YD/T 1082
- YD/T 993
- YD/T 950

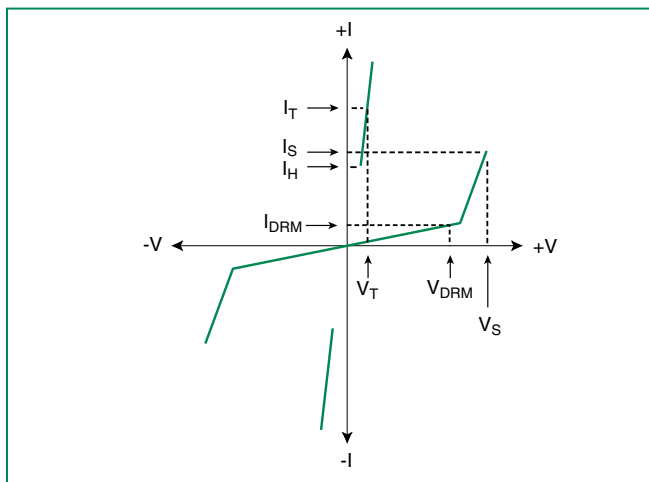
Electrical Characteristics

Part Number	Marking	$V_{DRM} @ I_{DRM}=5\mu A$	$V_S @ 100V/\mu s$	I_H	I_S	I_T	$V_T @ I_T=2.2$ Amps	Capacitance
		V min	V max	mA min	mA max	A max	V max	
SDP0080Q38CB	SDP-8C	6	25	50	800	2.2	8	See Capacitance vs Voltage Chart
SDP0220Q38CB	SDP02C	16	30	50	800	2.2	8	
SDP0640Q38CB	SDP06C	58	77	150	800	2.2	8	
SDP0720Q38CB	SDP07C	65	88	150	800	2.2	8	
SDP0900Q38CB	SDP09C	75	98	150	800	2.2	8	
SDP1100Q38CB	SDP11C	90	130	150	800	2.2	8	
SDP1300Q38CB	SDP13C	120	160	150	800	2.2	8	
SDP1800Q38CB	SDP18C	170	220	150	800	2.2	8	
SDP2600Q38CB	SDP26C	220	300	150	800	2.2	8	
SDP3100Q38CB	SDP31C	275	350	150	800	2.2	8	
SDP3500Q38CB	SDP35C	320	400	150	800	2.2	8	

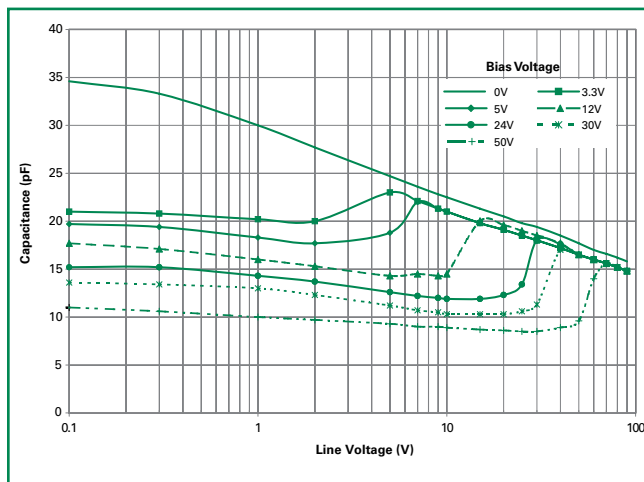
Notes:

- Absolute maximum ratings measured at $T_A = 25^\circ C$ (unless otherwise noted).
- Devices are bi-directional (unless otherwise noted).
- Part with * is under development.

V-I: Characteristics



Capacitance vs. Voltage*



* Bias voltage must be lower than V_{DRM}

50/60Hz Ratings

Parameter Name	Test Conditions	Value	Units
I_{TSM} Maximum non-repetitive on-state current, 50/60Hz	0.5s	6.5	A
	1s	4.6	
	2s	3.4	
	5s	2.3	
	30s	1.3	
	900s	0.73	

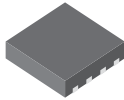
Surge Ratings

Series	I_{PP}				I_{TSM}
	2x10 μ s	1.2x50 μ s/8x20 μ s	10x700/5x310 μ s	10x1000 μ s	600V _{RMS} 1 cycle
	A min	A min	A min	A min	A _{RMS}
C	500	400	200	100	30

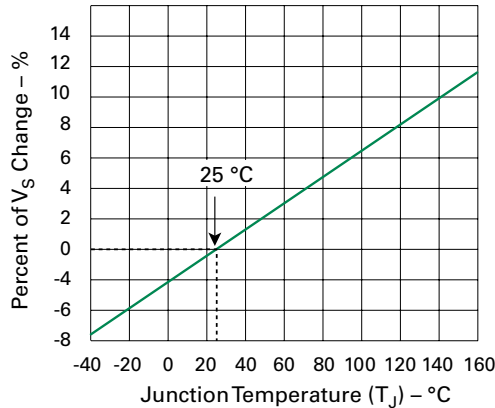
Notes:

- Peak pulse current rating (I_{pp}) is repetitive and guaranteed for the life of the product.
- I_{pp} ratings applicable over temperature range of -40°C to +85°C
- The device must initially be in thermal equilibrium with -40°C $\leq T_j \leq$ +150°C

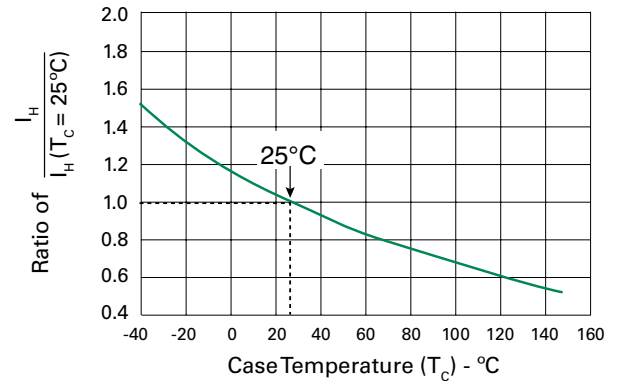
Thermal Considerations

Package	Symbol	Parameter	Value	Unit
 5x6 QFN	T_J	Junction Temperature	-40 to +150	°C
	T_{STG}	Storage Temperature Range	-40 to +150	°C
	$R_{\theta JA}$	Thermal Resistance: Junction to Ambient	100	°C/W

Normalized V_S Change vs. Junction Temperature

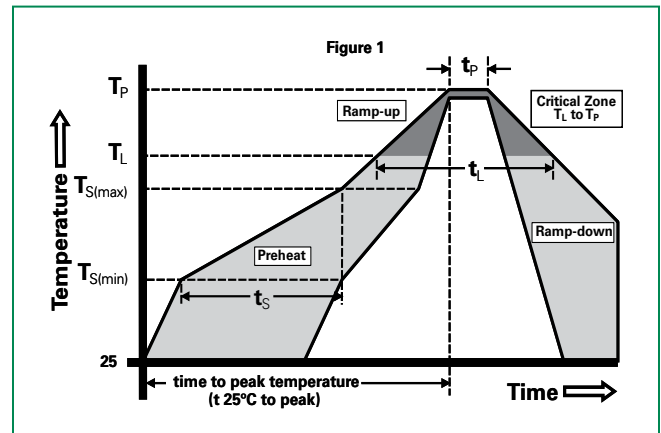


Normalized DC Holding Current vs. Case Temperature



Soldering Parameters

Reflow Condition		Pb-Free assembly (see Fig. 1)
Pre Heat	-Temperature Min ($T_{s(\min)}$)	+150°C
	-Temperature Max ($T_{s(\max)}$)	+200°C
	-Time (Min to Max) (t_s)	60-180 secs.
Average ramp up rate (Liquidus Temp (T_L) to peak)		3°C/sec. Max.
$T_{s(\max)}$ to T_L - Ramp-up Rate		3°C/sec. Max.
Reflow	-Temperature (T_L) (Liquidus)	+217°C
	-Temperature (t_L)	60-150 secs.
Peak Temp (T_P)		+260(+0/-5)°C
Time within 5°C of actual Peak Temp (t_p)		30 secs. Max.
Ramp-down Rate		6°C/sec. Max.
Time 25°C to Peak Temp (T_P)		8 min. Max.
Do not exceed		+260°C



Physical Specifications

Lead Material	Copper Alloy
Terminal Finish	100% Matte-Tin Plated
Body Material	UL recognized epoxy meeting flammability classification 94V-0

Additional Information



Datasheet



Resources

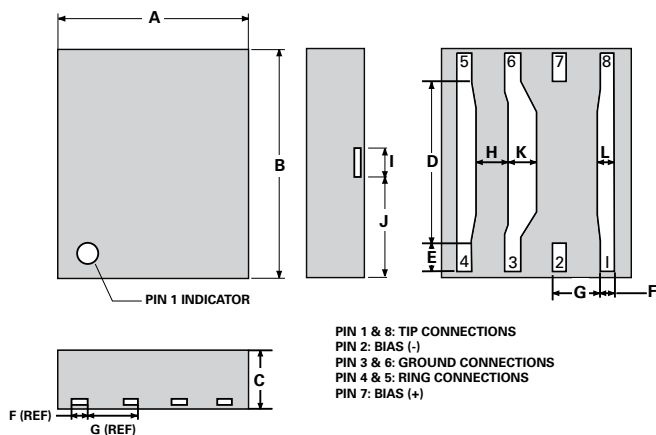


Samples

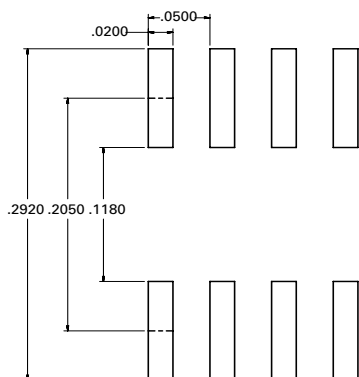
Environmental Specifications

High Temp Voltage Blocking	80% Rated V_{DRM} (V_{AC} Peak) +125°C or +150°C, 504 or 1008 hrs. MIL-STD-750 (Method 1040) JEDEC, JESD22-A-101
Temp Cycling	-65°C to +150°C, 15 min. dwell, 10 up to 100 cycles. MIL-STD-750 (Method 1051) EIA/JEDEC, JESD22-A-104
Biased Temp & Humidity	52 V_{DC} (+85°C) 85%RH, 504 up to 1008 hrs. EIA/JEDEC, JESD22-A-101
High Temp Storage	+150°C 1008 hrs. MIL-STD-750 (Method 1031) JEDEC, JESD22-A-101
Low Temp Storage	-65°C, 1008 hrs.
Thermal Shock	0°C to +100°C, 5 min. dwell, 10 sec. transfer, 10 cycles. MIL-STD-750 (Method 1056) JEDEC, JESD22-A-106
Resistance to Solder Heat	+260°C, 30 secs. MIL-STD-750 (Method 2031)
Moisture Sensitivity Level	85%RH, +85°C, 168 hrs., 3 reflow cycles (+260°C Peak). JEDEC-J-STD-020, Level 1

Dimensions — 5x6 QFN

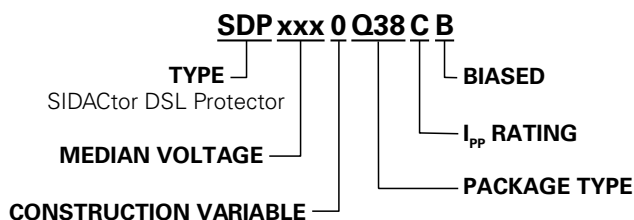


5x6 QFN Solder Pad Layout

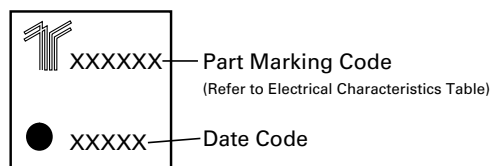


Dimension	Inches		Millimeters	
	Min	Max	Min	Max
A	0.187	0.207	4.745	5.253
B	0.226	0.246	5.745	6.253
C	0.054	0.064	1.374	1.628
D	0.165	0.171	4.199	4.351
E	0.027	0.033	0.686	0.838
F	0.011	0.017	0.279	0.432
G	0.047	0.053	1.194	1.346
H	0.032	0.038	0.800	0.953
I	0.027	0.033	0.686	0.838
J	0.100	0.106	2.540	2.692
K	0.027	0.033	0.686	0.838
L	0.015	0.021	0.381	0.533

Part Numbering



Part Marking

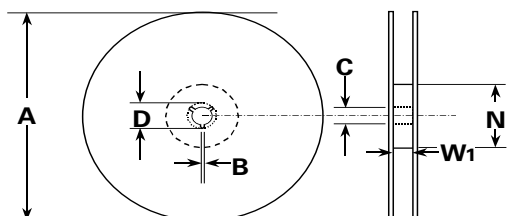


Packing Options

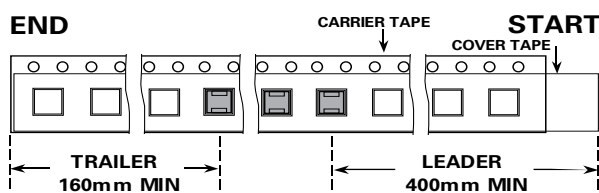
Package Type	Description	Quantity	Added Suffix	Industry Standard
Q38	5x6x1.5 QFN Tape and Reel Pack	4000	N/A	EIA-481-D

Tape and Reel Specifications — 5x6 QFN

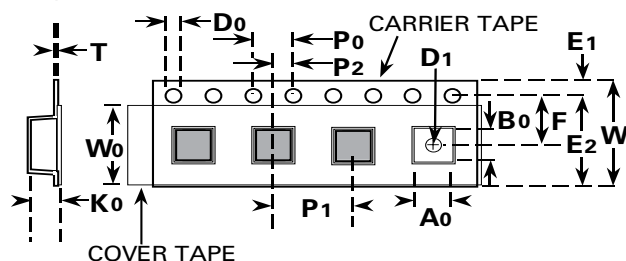
Reel Dimension



Tape Leader and Trailer Dimensions



Tape Dimension Items



Symbols	Description	Inches		Millimeters	
		Min	Max	Min	Max
A	Reel Diameter	N/A	12.992	N/A	330.0
B	Drive Spoke Width	0.059	N/A	1.50	N/A
C	Arbor Hole Diameter	0.504	0.531	12.80	13.50
D	Drive Spoke Diameter	0.795	N/A	20.20	N/A
N	Hub Diameter	1.969	N/A	50.00	N/A
W₁	Reel Inner Width at Hub	0.488	0.567	12.40	14.40
A₀	Pocket Width at Bottom	0.204	0.212	5.20	5.40
B₀	Pocket Length at Bottom	0.244	0.252	6.20	6.40
D₀	Feed Hole Diameter	0.059	0.063	1.50	1.60
D₁	Pocket Hole Diameter	0.059	N/A	1.50	N/A
E₁	Feed Hole Position 1	0.065	0.073	1.65	1.85
E₂	Feed Hole Position 2	0.400	0.408	10.15	10.35
F	Feed Hole Center - Pocket Hole Center 2	0.212	0.220	5.40	5.60
K₀	Pocket Depth	0.067	0.075	1.70	1.90
P₀	Feed Hole Pitch	0.153	0.161	3.90	4.10
P₁	Component Spacing	0.311	0.319	7.90	8.10
P₂	Feed Hole Center - Pocket Hole Center 1	0.077	0.081	1.90	2.10
T	Carrier Tape Thickness	0.010	0.014	0.25	0.35
W	Embossed Carrier Tape Width	0.460	0.484	11.70	12.30
W₀	Cover Tape Width	0.358	0.366	9.10	9.30